



44 FARRAND STREET
BLOOMFIELD, NJ 07003
(973) 748-5089

NTE5906, NTE5907, NTE5980 thru NTE6005 Silicon Power Rectifier Diode, 40 Amp

Features:

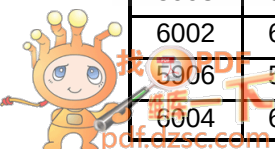
- High Surge Current Capability
- High Voltage Available
- Designed for a Wide Range of Applications
- Available in Anode-to-Case or Cathode-to-Case Style

Ratings and Characteristics:

Average Forward Current ($T_C = +140^\circ\text{C}$ Max), $I_{F(AV)}$	40A
Maximum Forward Surge Current, I_{FSM}	
50Hz	480A
60Hz	500A
Fusing Current, I^2t	
50Hz	1150A ² s
60Hz	1050A ² s
Fusing Current, $I^2\sqrt{t}$	16000A ² $\sqrt{s}$
Maximum Reverse Recovery Voltage Range, V_{RRM}	50 to 1600V

Voltage Ratings:

NTE Type Number		V_{RRM} -Max Repetitive Peak Reverse Volt. (V)	V_{RSM} -Max Non-Repetitive Peak Reverse Voltage (V) $t_p < 5\text{ms}$	V_R -Max. Direct Reverse Voltage (V)	$V_{R(SR)}$ Minimum Avalanche Voltage (V)	I_{RM} -Max Reverse Current Rated V_{RRM} (mA)
Cathode to Case	Anode to Case	$T_J = -65^\circ\text{ to }+150^\circ\text{C}$	$T_J = +25^\circ\text{ to }+150^\circ\text{C}$	$T_J = -65^\circ\text{ to }+150^\circ\text{C}$	$T_J = +25^\circ\text{C}$	$T_J = +150^\circ\text{C}$
5980	5981	50	100	50	—	15
5982	5983	100	200	100	—	15
5986	5987	200	300	200	—	15
5988	5989	300	450	300	—	15
5990	5991	400	500	400	500	15
5992	5993	500	600	500	600	9
5994	5995	600	720	600	725	9
5998	5999	800	960	800	960	9
6002	6003	1000	1200	1000	1150	9
5906	5907	1200	1400	1200	1350	9
6004	6005	1600	1700	1600	1700	9



Electrical Specifications:

Parameter	Symbol	Test Conditions	Rating	Unit
Maximum Average Forward Current	$I_F (AV)$	180° sinusoidal condition, $T_C = +140^{\circ}C$ Max	40	A
Maximum Peak One–Cycle Non–Repetitive Surge Current	I_{FSM}	Half cycle 50Hz sine wave or 8ms rectangular pulse	480	A
		Half cycle 60Hz sine wave at 5ms rectangular pulse		
		Half cycle 50Hz sine wave or 6ms rectangular pulse	500	A
		Half cycle 60Hz sine wave at 3ms rectangular pulse	570	A
Maximum I^2t for Fusing	I^2t	$t = 10ms$	Following any rated load condition and with rated V_{RRM} applied	480
		$t = 8.3ms$	Following any rated load condition and with V_{RRM} applied following surge = 0	500
Maximum I^2t for Individual Device Fusing	I^2t	$t = 10ms$	Following any rated load condition and with V_{RRM} applied following surge = 0	570
		$t = 8.3ms$	Following any rated load condition and with V_{RRM} applied following surge = 0	586
Maximum I^2t for Fusing	I^2t	$t = 10ms$	With rated V_{RRM} ap- plied following surge	1150
		$t = 8.3ms$	With rated V_{RRM} ap- plied following surge	1050
Maximum I^2t for Individual Device Fusing	I^2t	$t = 10ms$	With $V_{RRM} = 0$ fol- lowing surge	1600
		$t = 8.3ms$	With $V_{RRM} = 0$ fol- lowing surge	1450
Maximum $I^2\sqrt{t}$	$I^2\sqrt{t}$	$t = 0.1$ to $10ms$, $V_{RRM} = 0$ following surge	16000	$A^2\sqrt{t}$
Maximum Peak Forward Voltage	V_{FM}	$I_F (AV) = 40A$ (125 peak), $T_J = +25^{\circ}C$	1.30	V
Maximum Value of Threshold Voltage	$V_M (TO)$	$T_J = +100^{\circ}C$	0.69	V
Maximum Value of Forward Slope Resistance	r_t	$T_J = +100^{\circ}C$	3.79	$m\Omega$

Thermal–Mechanical Specifications:

Parameter	Symbol	Test Conditions	Rating	Unit
Maximum Operation Junction Temperature	T_J		–65 to + 190	$^{\circ}C$
Maximum Storage Temperature	T_{stg}		–65 to + 190	$^{\circ}C$
Maximum Internal Thermal Resistance Junction–to–Case	R_{thJC}	DC operation	1.00	K/W
Thermal Resistance, Case–to–Sink	R_{thCS}	Mounting surface flat, smooth and greased	0.25	K/W
Mounting Torque	T	Non–lubricated threads	2.3 – 3.4 (20 – 30)	$m\bullet N$ ($in\bullet lb$)
Approximate Weight	wt		17 (0.8)	g (oz)

